Supporting information: High-performance planar thin film thermochromic window via dynamic optical impedance matching

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Figure S1: (a-d) Measured ellipsometric parameters Δ (a, c) and Ψ (b, d) for a single VO₂ thin film along with corresponding theoretical fitting for 96 nm thickness using $VO₂(M)$ (a, b) and $VO₂(R)$ (c, d) optical constants as shown in the main text for multiple angles of incidence (AOI) normal from the sample surface.

Figure S2: Optical constants of impedance matching layers as derived from ellipsometry.

Figure S3: Identification of crystalline material phases within the sample. (a) Raman spectrum of sample. The peaks at ~140, 192, 223, 260, 308, 338, 387, 395, 440, 482, 497, 588, 613, 661 and 823 cm⁻¹ are assigned to the VO₂(M1) phase[1, 2, 3]. The broad peak at ~ 613 cm⁻¹ is a convolution of the peaks at 588, 613 and 661 cm−1. The low frequency phonons at 192 and 223 cm−1 correspond to lattice motion involving V-V bonds[4], whilst the peak at 140 cm−1 has previously been attributed to soft-phonon vibrations[2, 5]. The rest of the peaks are assigned to vibrational modes of V-O bonds[4, 6]. (b) X-ray diffraction spectrum of sample showing peaks for both $TiO₂(A)$ (101)[7] and VO² (M1) (011, 220)[8, 9].

Figure S4: Characterisation of visible haze. Fraction of the transmitted light that is outside 2° from normal is below 0.5% across the full visible range.

Figure S5: Additional electron microscopy images of fabricated structure. (a) Side-on image at 93000x magnification (b) Side-on image at 117000x magnification.

References

- [1] Pan, M. *et al.* Raman study of the phase transition in VO₂ thin films. *Journal of Crystal Growth* **268**, 178–183 (2004).
- [2] Schilbe, P. Raman scattering in VO₂. *Physica B: Condensed Matter* **316**, 600–602 (2002).
- [3] Petrov, G., Yakovlev, V. & Squier, J. Raman microscopy analysis of phase transformation mechanisms in vanadium dioxide. *Applied Physics Letters* **81**, 1023–1025 (2002).
- [4] Marini, C. *et al.* Optical properties of V1−*𝑥*Cr*𝑥*O² compounds under high pressure. *Physical Review B* **77**, 235111 (2008).
- [5] Goncharuk, I., Ilinskiy, A., Kvashenkina, O. & Shadrin, E. Electron-electron correlations in Raman spectra of VO₂. *Physics of the Solid State* **55**, 164–174 (2013).
- [6] Ureña-Begara, F., Crunteanu, A. & Raskin, J.-P. Raman and XPS characterization of vanadium oxide thin films with temperature. *Applied Surface Science* **403**, 717–727 (2017).
- [7] Ye, L. *et al.* Synthesis of anatase TiO₂ nanocrystals with $\{101\}$, $\{001\}$ or $\{010\}$ single facets of 90% level exposure and liquid-phase photocatalytic reduction and oxidation activity orders. *Journal of Materials Chemistry A* **1**, 10532–10537 (2013).
- [8] Cao, X. *et al.* Solution-based fabrication of VO₂(M) nanoparticles via lyophilisation. *RSC Advances* **5**, 25669–25675 (2015).
- [9] Jo, Y., Kim, M. & Kim, B. Direct correlation of structural and electrical properties of electrondoped individual VO² nanowires on devised TEM grids. *Nanotechnology* **27**, 435704–435704 (2016).